

These devices combine a dewar type detector with a compatible preamplifier, and easily operate to detect infrared radiation just by connecting to a DC power supply. InGaAs and InSb detectors are provided as standard devices (liquid nitrogen cooling). Custom-designed devices with different active areas, FOV or amplifier gain, etc. are also available to meet your specific needs.

Features

Compact integral detector unit

Optimum connections between the detector element and preamplifier allow amplified signals to be easily obtained.

Required power supply specifications

- · G7754 series, P7751 series: ±15 V (±12.0 to ±17.5 V can also be used)
- · Current capacity: 1.5 times or more of each module's maximum current consumption
- · Ripple noise: 5 mVp-p or less
- · Analog power supply only
- · Recommended DC power supplies:
- E3620A, E3630A (Agilent Technologies)

- Applications

- Infrared detection
- Accessories
- Cable (for DC power supply):
 2 m (connector installed at one end)
- BNC-BNC coaxial cable (for signal output): 2 m

A4372-02

Instruction manual

Specifications / Absolute maximum ratings

	Detector element		External power supply ^{*1}				Absolute maximum ratings		
Type No.		Active area	Supply voltage (V)			Supply capacitance	External input voltage	Operating temperature Topr	Storage temperature Tstg
		(mm)	Min.	Тур.	Max.	(mA)	(V)	(°C)	(°C)
G7754-01	InGaAs (G12183-010 chip)	φ1				±23			
G7754-03	InGaAs (G12183-030 chip)	фЗ	φ3 ±12.0		±17.5	123	±18	0 to +40	-20 to +50
P7751-01	InSb (P5968-060)	ф0.6]			±30			
P7751-02	InSb (P5968-200)	φ2							

*1: Use only an analog power supply.

Note: Nitrogen hold time: 12 hours or more (at the time of shipment)

Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

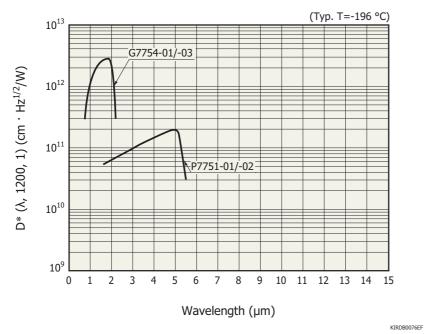
Electrical and optical characteristics (Typ.)

Type No.	Measurement condition Element temperature T	Peak sensitivity wavelength	Cut-off wavelength λc	Photo sensitivity S $\lambda = \lambda p$ *2	Noise equivalent power NEP $\lambda = \lambda p$	Cutoff frequency fc	Output impedance	Maximum output voltage RL=1 kΩ	Maximum current consumption* ³
	(°C)	(µm)	(µm)	(V/W)	(W/Hz ^{1/2})	(Hz)	(Ω)	(V)	(mA)
G7754-01	-196	2.0	2.4	2×10^{9}	3×10^{-14}	2 to 500	50	±10	±15
G7754-03				5×10^{8}	1.5×10^{-13}	2 to 500		±10	±15
P7751-01*4		5.3	5.5	3×10^{8}	3×10^{-13}	5 to 10000	50	±10	±20
P7751-02*4				1.5×10^{8}	1×10^{-12}	5 to 12000		±10	±20

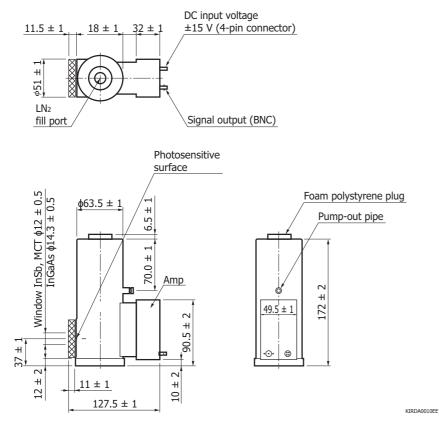
*2: f=100 Hz (G7754-01, G7754-03), f=1.2 kHz (P7751-01, P7751-02)

^{*3:} Vs=±15 V *4: FOV=60°

Spectral response

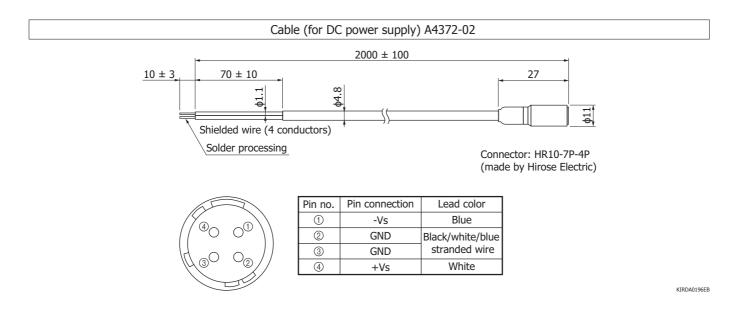


Dimensional outline (unit: mm)





Infrared detector modules with preamps



Precaution for use

- The detector should not be placed horizontally during use.
- · Using these detectors in an environment subjected to vibration may cause microphonic noise. Take measures to prevent vibration as needed.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- Notice
- Technical information
- Infrared detector

Information described in this material is current as of November, 2014.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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www.hamamatsu.com

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Cat. No. KIRD1024E10 Nov. 2014 DN